To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT1065T

Silicon P Channel MOS FET
High Speed Power Switching

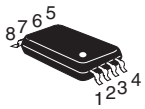
REJ03G0161-0200
Rev.2.00
Aug 06, 2007

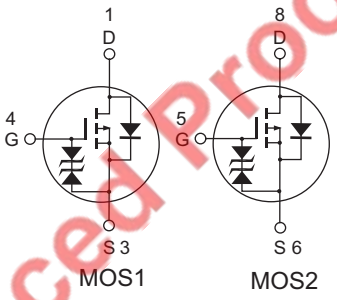
Features

- Low on-resistance
- Capable of –4 V gate drive
- High density mounting

Outline

RENESAS Package code: PTSP0008JB-B
(Package name: TSSOP-8 <TTP-8DV>)





1, 8	Drain
3, 6	Source
4, 5	Gate
2, 7	NC

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	–200	V
Gate to source voltage	V_{GSS}	±15	V
Drain current	I_D	–0.25	A
Drain peak current	$I_{D(pulse)}$ Note1	–1	A
Body-drain diode reverse drain current	I_{DR}	–0.25	A
Channel dissipation	Pch Note2	1	W
Channel dissipation	Pch Note3	1.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	°C

Notes: 1. PW ≤ 10 µs, duty cycle ≤ 1 %
2. 1 Drive operation ; When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW ≤ 10 s
3. 2 Drive operation ; When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW ≤ 10 s

Electrical Characteristics

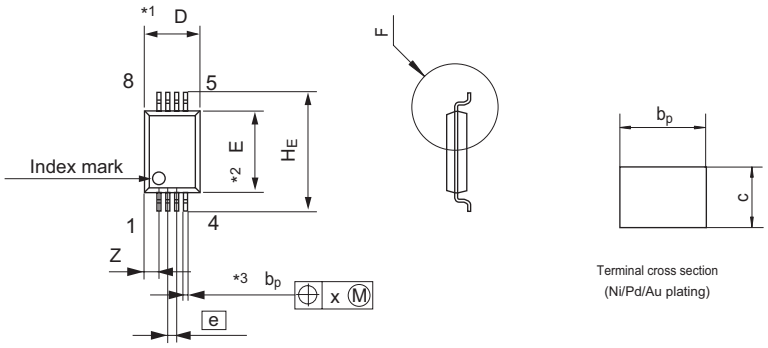
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	–200	—	—	V	I_D = –10 mA, V_{GS} = 0
Gate to source breakdown voltage	$V_{(BR)GSS}$	±15	—	—	V	I_G = ±100 µA, V_{DS} = 0
Gate to source leak current	I_{GSS}	—	—	±10	µA	V_{GS} = ±12 V, V_{DS} = 0
Zero gate voltage drain current	I_{DSS}	—	—	–5	µA	V_{DS} = –200 V, V_{GS} = 0
Gate to source cutoff voltage	$V_{GS(off)}$	–1.0	—	–2.0	V	V_{DS} = –10 V, I_D = –1 mA
Static drain to source on state resistance	$R_{DS(on)}$	—	5.0	6.2	Ω	I_D = –0.25 A, V_{GS} = –10 V Note4
	$R_{DS(on)}$	—	6.0	7.5	Ω	I_D = –0.25 A, V_{GS} = –4 V Note4
	$R_{DS(on)}$	—	7.0	10.0	Ω	I_D = –1 A, V_{GS} = –5 V Note4
Forward transfer admittance	$\|y_{fs}\|$	0.29	0.45	—	S	I_D = –0.25 A, V_{DS} = –10 V Note4
Input capacitance	Ciss	—	140	—	pF	V_{DS} = –10 V V_{GS} = 0 f = 1 MHz
Output capacitance	Coss	—	37	—	pF	
Reverse transfer capacitance	Crss	—	10	—	pF	
Turn-on delay time	$t_{d(on)}$	—	12	—	ns	V_{GS} = –5 V, I_D = –0.25 A V_{DD} ≅ –30 V
Rise time	t_r	—	9	—	ns	
Turn-off delay time	$t_{d(off)}$	—	25	—	ns	
Fall time	t_f	—	15	—	ns	
Body–drain diode forward voltage	V_{DF}	—	–0.9	–1.4	V	I_F = –0.25 A, V_{GS} = 0 Note4

Notes: 4. Pulse test

Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TSSOP-8	P-TSSOP8-4.4 × 3-0.65	PTSP0008JB-B	TTP-8DV	0.034g



NOTE)
1. DIMENSIONS "*1(Nom)" AND "*2" DO NOT INCLUDE MOLD FLASH.
2. DIMENSION "*3" DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	3.00	3.30
E	—	4.40	—
A_2	—	—	—
A_1	0.03	0.07	0.10
A	—	—	1.10
b_p	0.15	0.20	0.25
b_1	—	—	—
c	0.10	0.15	0.20
c_1	—	—	—
θ	0°	—	8°
H_E	6.20	6.40	6.60
e	—	0.65	—
x	—	—	0.13
y	—	—	0.10
Z	—	—	0.805
L	0.40	0.50	0.60
L_1	—	1.0	—

Ordering Information

Part No.	Quantity	Shipping Container
HAT1065T-EL-E	3000 pcs	Taping

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http://www.renesas.com

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